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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Discontinued at Digi-Key
Core Processor	ARM® Cortex®-M0+
Core Size	32-Bit Single-Core
Speed	48MHz
Connectivity	CANbus, I <sup>2</sup> C, IrDA, LINbus, SmartCard, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, I <sup>2</sup> S, LCD, POR, PWM, WDT
Number of I/O	53
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	32K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.8V
Data Converters	A/D 12bit SAR; D/A 12bit
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TJ)
Mounting Type	Surface Mount
Package / Case	64-VFQFN Exposed Pad
Supplier Device Package	64-QFN (9x9)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/silicon-labs/efm32tg11b340f64im64-ar">https://www.e-xfl.com/product-detail/silicon-labs/efm32tg11b340f64im64-ar</a>

## 3.10 Core and Memory

### 3.10.1 Processor Core

The ARM Cortex-M processor includes a 32-bit RISC processor integrating the following features and tasks in the system:

- ARM Cortex-M0+ RISC processor
- Memory Protection Unit (MPU) supporting up to 8 memory segments
- Micro-Trace Buffer (MTB)
- Up to 128 kB flash program memory
- Up to 32 kB RAM data memory
- Configuration and event handling of all modules
- 2-pin Serial-Wire debug interface

### 3.10.2 Memory System Controller (MSC)

The Memory System Controller (MSC) is the program memory unit of the microcontroller. The flash memory is readable and writable from both the Cortex-M and DMA. The flash memory is divided into two blocks; the main block and the information block. Program code is normally written to the main block, whereas the information block is available for special user data and flash lock bits. There is also a read-only page in the information block containing system and device calibration data. Read and write operations are supported in energy modes EM0 Active and EM1 Sleep.

### 3.10.3 Linked Direct Memory Access Controller (LDMA)

The Linked Direct Memory Access (LDMA) controller allows the system to perform memory operations independently of software. This reduces both energy consumption and software workload. The LDMA allows operations to be linked together and staged, enabling sophisticated operations to be implemented.

### 3.10.4 Bootloader

All devices come pre-programmed with a UART bootloader. This bootloader resides in flash and can be erased if it is not needed. More information about the bootloader protocol and usage can be found in *AN0003: UART Bootloader*. Application notes can be found on the Silicon Labs website ([www.silabs.com/32bit-appnotes](http://www.silabs.com/32bit-appnotes)) or within Simplicity Studio in the [Documentation] area.

#### 4.1.2.1 General Operating Conditions

Table 4.2. General Operating Conditions

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Operating ambient temperature range <sup>6</sup>	$T_A$	-G temperature grade	-40	25	85	°C
		-I temperature grade	-40	25	125	°C
AVDD supply voltage <sup>2</sup>	$V_{AVDD}$		1.8	3.3	3.8	V
VREGVDD operating supply voltage <sup>2 1</sup>	$V_{VREGVDD}$	DCDC in regulation	2.4	3.3	3.8	V
		DCDC in bypass, 50mA load	1.8	3.3	3.8	V
		DCDC not in use. DVDD externally shorted to VREGVDD	1.8	3.3	3.8	V
VREGVDD current	$I_{VREGVDD}$	DCDC in bypass, $T \leq 85^\circ\text{C}$	—	—	200	mA
		DCDC in bypass, $T > 85^\circ\text{C}$	—	—	100	mA
DVDD operating supply voltage	$V_{DVDD}$		1.62	—	$V_{VREGVDD}$	V
IOVDD operating supply voltage	$V_{IOVDD}$	All IOVDD pins <sup>5</sup>	1.62	—	$V_{VREGVDD}$	V
DECOUPLE output capacitor <sup>3 4</sup>	$C_{DECOUPLE}$		0.75	1.0	2.75	μF
HFCORECLK frequency	$f_{CORE}$	VSCALE2, MODE = WS1	—	—	48	MHz
		VSCALE2, MODE = WS0	—	—	25	MHz
		VSCALE0, MODE = WS1	—	—	20	MHz
		VSCALE0, MODE = WS0	—	—	10	MHz
HFCLK frequency	$f_{HFCLK}$	VSCALE2	—	—	48	MHz
		VSCALE0	—	—	20	MHz
HFSRCCLK frequency	$f_{HFSRCCLK}$	VSCALE2	—	—	48	MHz
		VSCALE0	—	—	20	MHz
HFBUSCLK frequency	$f_{HFBUSCLK}$	VSCALE2	—	—	48	MHz
		VSCALE0	—	—	20	MHz
HFPERCLK frequency	$f_{HFPERCLK}$	VSCALE2	—	—	48	MHz
		VSCALE0	—	—	20	MHz
HFPERBCLK frequency	$f_{HFPERBCLK}$	VSCALE2	—	—	48	MHz
		VSCALE0	—	—	20	MHz
HFPERCCLK frequency	$f_{HFPERCCLK}$	VSCALE2	—	—	48	MHz
		VSCALE0	—	—	20	MHz

## 4.1.5 Backup Supply Domain

**Table 4.5. Backup Supply Domain**

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Backup supply voltage range	V <sub>BU_VIN</sub>		TBD	—	3.8	V
PWRRES resistor	R <sub>PWRRES</sub>	EMU_BUCTRL_PWRRES = RES0	TBD	3900	TBD	Ω
		EMU_BUCTRL_PWRRES = RES1	TBD	1800	TBD	Ω
		EMU_BUCTRL_PWRRES = RES2	TBD	1330	TBD	Ω
		EMU_BUCTRL_PWRRES = RES3	TBD	815	TBD	Ω
Output impedance between BU_VIN and BU_VOUT <sup>2</sup>	R <sub>BU_VOUT</sub>	EMU_BUCTRL_VOUTRES = STRONG	TBD	110	TBD	Ω
		EMU_BUCTRL_VOUTRES = MED	TBD	775	TBD	Ω
		EMU_BUCTRL_VOUTRES = WEAK	TBD	6500	TBD	Ω
Supply current	I <sub>BU_VIN</sub>	BU_VIN not powering backup domain	—	10	TBD	nA
		BU_VIN powering backup domain <sup>1</sup>	—	450	TBD	nA

**Note:**  
1. Additional current required by backup circuitry when backup is active. Includes supply current of backup switches and backup regulator. Does not include supply current required for backed-up circuitry.  
2. BU\_VOUT and BU\_STAT signals are not available in all package configurations. Check the device pinout for availability.

#### 4.1.6.2 Current Consumption 3.3 V using DC-DC Converter

Unless otherwise indicated, typical conditions are: VREGVDD = AVDD = IOVDD = 3.3 V, DVDD = 1.8 V DC-DC output. T = 25 °C. Minimum and maximum values in this table represent the worst conditions across supply voltage and process variation at T = 25 °C.

**Table 4.7. Current Consumption 3.3 V using DC-DC Converter**

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Current consumption in EM0 mode with all peripherals disabled, DCDC in Low Noise DCM mode <sup>2</sup>	I <sub>ACTIVE_DCM</sub>	48 MHz crystal, CPU running while loop from flash	—	38	—	μA/MHz
		48 MHz HFRCO, CPU running while loop from flash	—	37	—	μA/MHz
		48 MHz HFRCO, CPU running Prime from flash	—	45	—	μA/MHz
		48 MHz HFRCO, CPU running CoreMark loop from flash	—	53	—	μA/MHz
		32 MHz HFRCO, CPU running while loop from flash	—	43	—	μA/MHz
		26 MHz HFRCO, CPU running while loop from flash	—	47	—	μA/MHz
		16 MHz HFRCO, CPU running while loop from flash	—	61	—	μA/MHz
		1 MHz HFRCO, CPU running while loop from flash	—	587	—	μA/MHz
Current consumption in EM0 mode with all peripherals disabled, DCDC in Low Noise CCM mode <sup>1</sup>	I <sub>ACTIVE_CCM</sub>	48 MHz crystal, CPU running while loop from flash	—	49	—	μA/MHz
		48 MHz HFRCO, CPU running while loop from flash	—	48	—	μA/MHz
		48 MHz HFRCO, CPU running Prime from flash	—	55	—	μA/MHz
		48 MHz HFRCO, CPU running CoreMark loop from flash	—	63	—	μA/MHz
		32 MHz HFRCO, CPU running while loop from flash	—	60	—	μA/MHz
		26 MHz HFRCO, CPU running while loop from flash	—	68	—	μA/MHz
		16 MHz HFRCO, CPU running while loop from flash	—	96	—	μA/MHz
		1 MHz HFRCO, CPU running while loop from flash	—	1157	—	μA/MHz
Current consumption in EM0 mode with all peripherals disabled, DCDC in LP mode <sup>3</sup>	I <sub>ACTIVE_LPM</sub>	32 MHz HFRCO, CPU running while loop from flash	—	32	—	μA/MHz
		26 MHz HFRCO, CPU running while loop from flash	—	33	—	μA/MHz
		16 MHz HFRCO, CPU running while loop from flash	—	36	—	μA/MHz
		1 MHz HFRCO, CPU running while loop from flash	—	156	—	μA/MHz

#### 4.1.9.4 High-Frequency RC Oscillator (HFRCO)

Table 4.14. High-Frequency RC Oscillator (HFRCO)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Frequency accuracy	$f_{\text{HFRCO\_ACC}}$	At production calibrated frequencies, across supply voltage and temperature	TBD	—	TBD	%
Start-up time	$t_{\text{HFRCO}}$	$f_{\text{HFRCO}} \geq 19 \text{ MHz}$	—	300	—	ns
		$4 < f_{\text{HFRCO}} < 19 \text{ MHz}$	—	1	—	$\mu\text{s}$
		$f_{\text{HFRCO}} \leq 4 \text{ MHz}$	—	2.5	—	$\mu\text{s}$
Current consumption on all supplies	$I_{\text{HFRCO}}$	$f_{\text{HFRCO}} = 48 \text{ MHz}$	—	258	TBD	$\mu\text{A}$
		$f_{\text{HFRCO}} = 38 \text{ MHz}$	—	218	TBD	$\mu\text{A}$
		$f_{\text{HFRCO}} = 32 \text{ MHz}$	—	182	TBD	$\mu\text{A}$
		$f_{\text{HFRCO}} = 26 \text{ MHz}$	—	156	TBD	$\mu\text{A}$
		$f_{\text{HFRCO}} = 19 \text{ MHz}$	—	130	TBD	$\mu\text{A}$
		$f_{\text{HFRCO}} = 16 \text{ MHz}$	—	112	TBD	$\mu\text{A}$
		$f_{\text{HFRCO}} = 13 \text{ MHz}$	—	101	TBD	$\mu\text{A}$
		$f_{\text{HFRCO}} = 7 \text{ MHz}$	—	80	TBD	$\mu\text{A}$
		$f_{\text{HFRCO}} = 4 \text{ MHz}$	—	29	TBD	$\mu\text{A}$
		$f_{\text{HFRCO}} = 2 \text{ MHz}$	—	26	TBD	$\mu\text{A}$
		$f_{\text{HFRCO}} = 1 \text{ MHz}$	—	24	TBD	$\mu\text{A}$
		$f_{\text{HFRCO}} = 40 \text{ MHz, DPLL enabled}$	—	393	TBD	$\mu\text{A}$
		$f_{\text{HFRCO}} = 32 \text{ MHz, DPLL enabled}$	—	313	TBD	$\mu\text{A}$
		$f_{\text{HFRCO}} = 16 \text{ MHz, DPLL enabled}$	—	180	TBD	$\mu\text{A}$
		$f_{\text{HFRCO}} = 4 \text{ MHz, DPLL enabled}$	—	46	TBD	$\mu\text{A}$
		$f_{\text{HFRCO}} = 1 \text{ MHz, DPLL enabled}$	—	33	TBD	$\mu\text{A}$
Coarse trim step size (% of period)	$SS_{\text{HFRCO\_COARSE}}$		—	0.8	—	%
Fine trim step size (% of period)	$SS_{\text{HFRCO\_FINE}}$		—	0.1	—	%
Period jitter	$PJ_{\text{HFRCO}}$		—	0.2	—	% RMS

#### 4.1.21.2 I2C Fast-mode (Fm)<sup>1</sup>

**Table 4.29. I2C Fast-mode (Fm)<sup>1</sup>**

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
SCL clock frequency <sup>2</sup>	f <sub>SCL</sub>		0	—	400	kHz
SCL clock low time	t <sub>LOW</sub>		1.3	—	—	μs
SCL clock high time	t <sub>HIGH</sub>		0.6	—	—	μs
SDA set-up time	t <sub>SU_DAT</sub>		100	—	—	ns
SDA hold time <sup>3</sup>	t <sub>HD_DAT</sub>		100	—	900	ns
Repeated START condition set-up time	t <sub>SU_STA</sub>		0.6	—	—	μs
(Repeated) START condition hold time	t <sub>HD_STA</sub>		0.6	—	—	μs
STOP condition set-up time	t <sub>SU_STO</sub>		0.6	—	—	μs
Bus free time between a STOP and START condition	t <sub>BUF</sub>		1.3	—	—	μs

**Note:**

1. For CLHR set to 1 in the I2Cn\_CTRL register.
2. For the minimum HPERCLK frequency required in Fast-mode, refer to the I2C chapter in the reference manual.
3. The maximum SDA hold time (t<sub>HD,DAT</sub>) needs to be met only when the device does not stretch the low time of SCL (t<sub>LOW</sub>).

## 4.1.22 USART SPI

### SPI Master Timing

Table 4.31. SPI Master Timing

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
SCLK period <sup>1 3 2</sup>	$t_{SCLK}$		$2 * t_{H\overline{F}PERCLK}$	—	—	ns
CS to MOSI <sup>1 3</sup>	$t_{CS\_MO}$		-19.8	—	18.9	ns
SCLK to MOSI <sup>1 3</sup>	$t_{SCLK\_MO}$		-10	—	14.5	ns
MISO setup time <sup>1 3</sup>	$t_{SU\_MI}$	IOVDD = 1.62 V	75	—	—	ns
		IOVDD = 3.0 V	40	—	—	ns
MISO hold time <sup>1 3</sup>	$t_{H\_MI}$		-10	—	—	ns

**Note:**

1. Applies for both CLKPHA = 0 and CLKPHA = 1 (figure only shows CLKPHA = 0).
2.  $t_{H\overline{F}PERCLK}$  is one period of the selected H $\overline{F}$ PERCLK.
3. Measurement done with 8 pF output loading at 10% and 90% of  $V_{DD}$  (figure shows 50% of  $V_{DD}$ ).

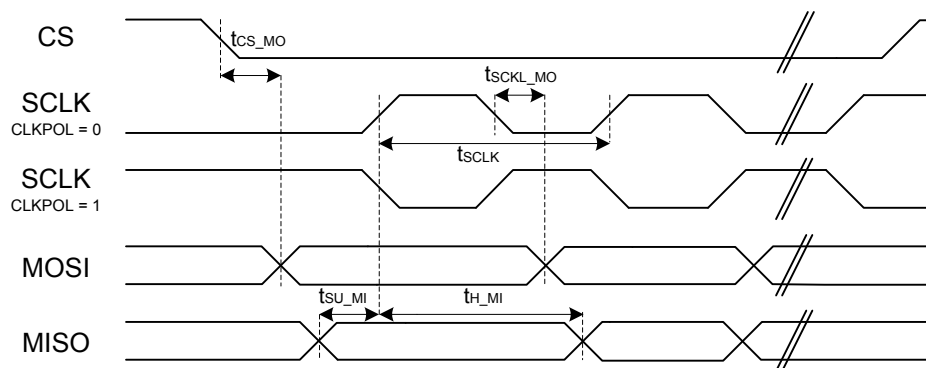
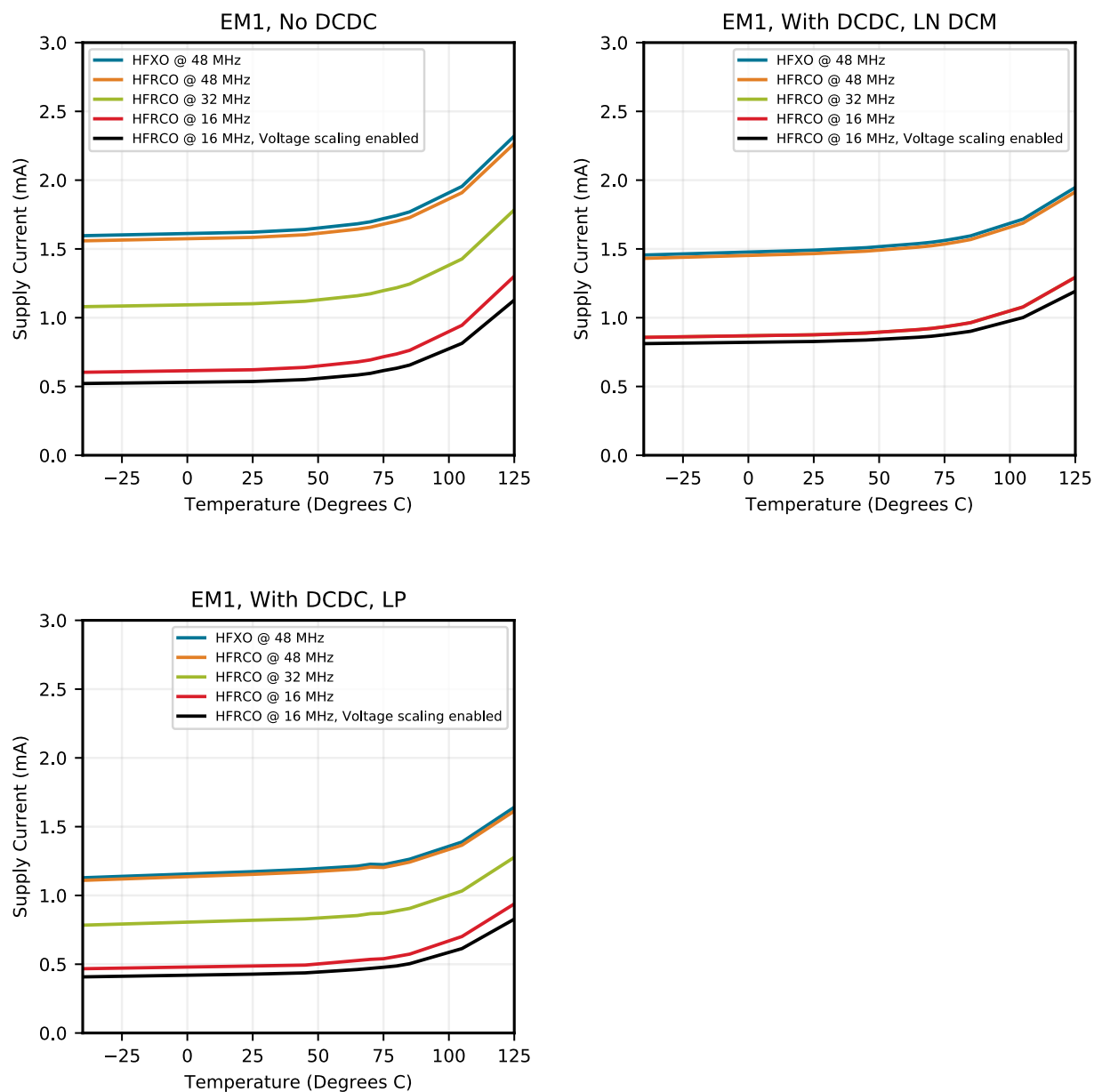


Figure 4.1. SPI Master Timing Diagram





**Figure 4.4. EM1 Sleep Mode Typical Supply Current vs. Temperature**

Typical supply current for EM2, EM3 and EM4H using standard software libraries from Silicon Laboratories.

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PC4	13	GPIO	PC5	14	GPIO
PB7	15	GPIO	PB8	16	GPIO
PA8	17	GPIO	PA9	18	GPIO
PA10	19	GPIO	RESETn	20	Reset input, active low. To apply an external reset source to this pin, it is required to only drive this pin low during reset, and let the internal pull-up ensure that reset is released.
PB11	21	GPIO	AVDD	23 27	Analog power supply.
PB13	24	GPIO	PB14	25	GPIO
PD0	28	GPIO (5V)	PD1	29	GPIO
PD2	30	GPIO (5V)	PD3	31	GPIO
PD4	32	GPIO	PD5	33	GPIO
PD6	34	GPIO	PD7	35	GPIO
PD8	36	GPIO	PC6	37	GPIO
PC7	38	GPIO	DVDD	39	Digital power supply.
DECOUPLE	40	Decouple output for on-chip voltage regulator. An external decoupling capacitor is required at this pin.	PC8	41	GPIO
PC9	42	GPIO	PC10	43	GPIO (5V)
PC11	44	GPIO (5V)	PC12	45	GPIO (5V)
PC13	46	GPIO (5V)	PC14	47	GPIO (5V)
PC15	48	GPIO (5V)	PF0	49	GPIO (5V)
PF1	50	GPIO (5V)	PF2	51	GPIO
PF3	52	GPIO	PF4	53	GPIO
PF5	54	GPIO	PE8	57	GPIO
PE9	58	GPIO	PE10	59	GPIO
PE11	60	GPIO	PE12	61	GPIO
PE13	62	GPIO	PE14	63	GPIO
PE15	64	GPIO			

**Note:**

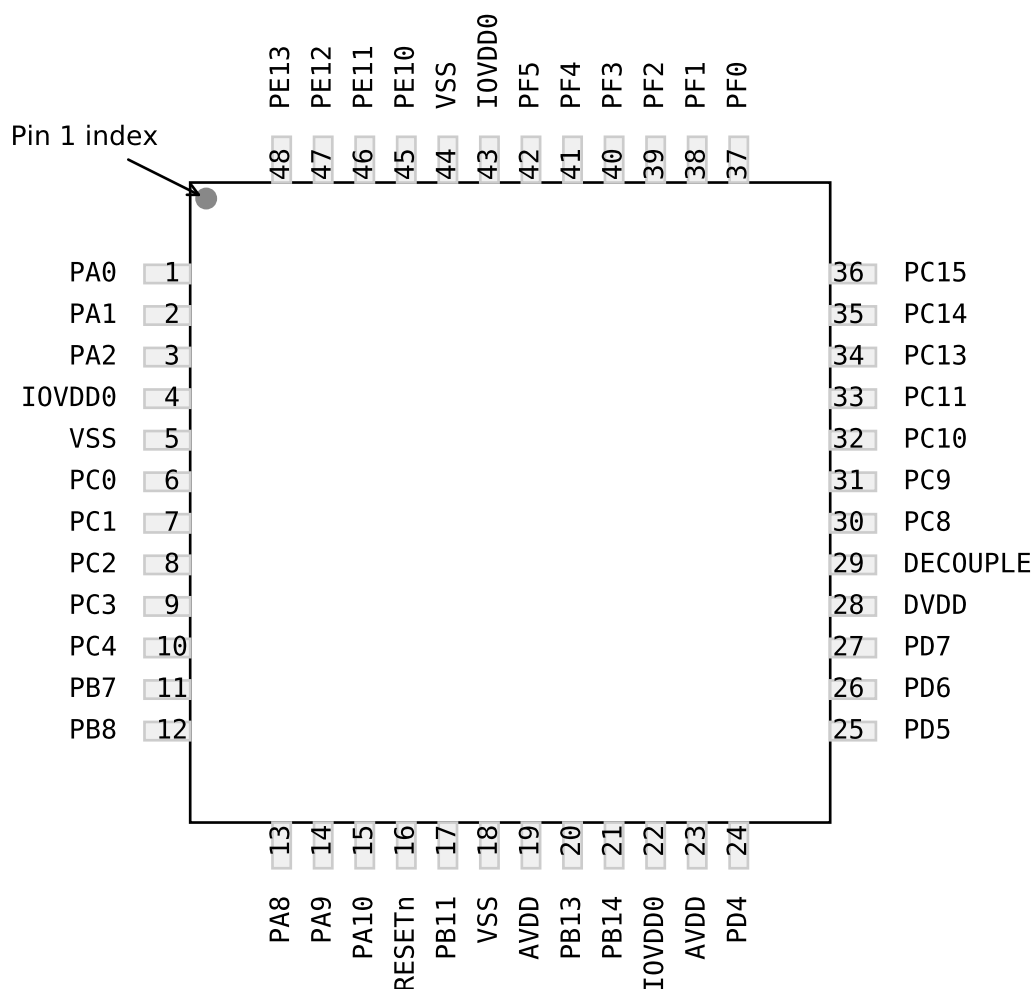
1. GPIO with 5V tolerance are indicated by (5V).

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PB4	10	GPIO	PB5	11	GPIO
PB6	12	GPIO	PC4	13	GPIO
PC5	14	GPIO	PB7	15	GPIO
PB8	16	GPIO	PA8	17	GPIO
PA12	18	GPIO	PA13	19	GPIO (5V)
PA14	20	GPIO	RESETn	21	Reset input, active low. To apply an external reset source to this pin, it is required to only drive this pin low during reset, and let the internal pull-up ensure that reset is released.
PB11	22	GPIO	PB12	23	GPIO
AVDD	24 28	Analog power supply.	PB13	25	GPIO
PB14	26	GPIO	PD0	29	GPIO (5V)
PD1	30	GPIO	PD3	31	GPIO
PD4	32	GPIO	PD5	33	GPIO
PD6	34	GPIO	PD7	35	GPIO
PD8	36	GPIO	PC7	37	GPIO
VREGSW	39	DCDC regulator switching node	VREGVDD	40	Voltage regulator VDD input
DVDD	41	Digital power supply.	DECOUPLE	42	Decouple output for on-chip voltage regulator. An external decoupling capacitor is required at this pin.
PE4	43	GPIO	PE5	44	GPIO
PE6	45	GPIO	PE7	46	GPIO
PC12	47	GPIO (5V)	PC13	48	GPIO (5V)
PF0	49	GPIO (5V)	PF1	50	GPIO (5V)
PF2	51	GPIO	PF3	52	GPIO
PF4	53	GPIO	PF5	54	GPIO
PE8	56	GPIO	PE9	57	GPIO
PE10	58	GPIO	PE11	59	GPIO
PE12	60	GPIO	PE13	61	GPIO
PE14	62	GPIO	PE15	63	GPIO
PA15	64	GPIO			

**Note:**

1. GPIO with 5V tolerance are indicated by (5V).

## 5.11 EFM32TG11B1xx in QFP48 Device Pinout



**Figure 5.11. EFM32TG11B1xx in QFP48 Device Pinout**

The following table provides package pin connections and general descriptions of pin functionality. For detailed information on the supported features for each GPIO pin, see [5.14 GPIO Functionality Table](#) or [5.15 Alternate Functionality Overview](#).

**Table 5.11. EFM32TG11B1xx in QFP48 Device Pinout**

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PA0	1	GPIO	PA1	2	GPIO
PA2	3	GPIO	IOVDD0	4 22 43	Digital IO power supply 0.
VSS	5 18 44	Ground	PC0	6	GPIO (5V)
PC1	7	GPIO (5V)	PC2	8	GPIO (5V)
PC3	9	GPIO (5V)	PC4	10	GPIO

Alternate	LOCATION		
Functionality	0 - 3	4 - 7	Description
LETIM0_OUT1	0: PD7 1: PB12 2: PF1 3: PC5	4: PE13 5: PC15 6: PA9	Low Energy Timer LETIM0, output channel 1.
LEU0_RX	0: PD5 1: PB14 2: PE15 3: PF1	4: PA0 5: PC15	LEUART0 Receive input.
LEU0_TX	0: PD4 1: PB13 2: PE14 3: PF0	4: PF2 5: PC14	LEUART0 Transmit output. Also used as receive input in half duplex communication.
LFXTAL_N	0: PB8		Low Frequency Crystal (typically 32.768 kHz) negative pin. Also used as an optional external clock input pin.
LFXTAL_P	0: PB7		Low Frequency Crystal (typically 32.768 kHz) positive pin.
OPA0_N	0: PC5		Operational Amplifier 0 external negative input.
OPA0_P	0: PC4		Operational Amplifier 0 external positive input.
OPA1_N	0: PD7		Operational Amplifier 1 external negative input.
OPA1_P	0: PD6		Operational Amplifier 1 external positive input.
OPA2_N	0: PD3		Operational Amplifier 2 external negative input.
OPA2_OUT	0: PD5		Operational Amplifier 2 output.
OPA2_OUTALT	0: PD0		Operational Amplifier 2 alternative output.
OPA2_P	0: PD4		Operational Amplifier 2 external positive input.

Alternate	LOCATION		
Functionality	0 - 3	4 - 7	Description
VDAC0_OUT0 / OPA0_OUT	0: PB11		Digital to Analog Converter DAC0 output channel number 0.
VDAC0_OUT0ALT / OPA0_OUTALT	0: PC0 1: PC1 2: PC2 3: PC3	4: PD0	Digital to Analog Converter DAC0 alternative output for channel 0.
VDAC0_OUT1 / OPA1_OUT	0: PB12		Digital to Analog Converter DAC0 output channel number 1.
VDAC0_OUT1ALT / OPA1_OUTALT	0: PC12 1: PC13 2: PC14 3: PC15	4: PD1	Digital to Analog Converter DAC0 alternative output for channel 1.
WTIM0_CC0	0: PE4 1: PA6	4: PC15  6: PB3 7: PC1	Wide timer 0 Capture Compare input / output channel 0.
WTIM0_CC1	0: PE5	4: PF0  6: PB4 7: PC2	Wide timer 0 Capture Compare input / output channel 1.
WTIM0_CC2	0: PE6	4: PF1  6: PB5 7: PC3	Wide timer 0 Capture Compare input / output channel 2.
WTIM0_CDTI0	0: PE10 2: PA12	4: PD4	Wide timer 0 Complimentary Dead Time Insertion channel 0.
WTIM0_CDTI1	0: PE11 2: PA13	4: PD5	Wide timer 0 Complimentary Dead Time Insertion channel 1.
WTIM0_CDTI2	0: PE12 2: PA14	4: PD6	Wide timer 0 Complimentary Dead Time Insertion channel 2.
WTIM1_CC0	0: PB13 1: PD2 2: PD6 3: PC7	5: PE7	Wide timer 1 Capture Compare input / output channel 0.
WTIM1_CC1	0: PB14 1: PD3 2: PD7	4: PE4	Wide timer 1 Capture Compare input / output channel 1.
WTIM1_CC2	0: PD0 1: PD4 2: PD8	4: PE5	Wide timer 1 Capture Compare input / output channel 2.



PF7 is available on port APORT2X as CH23, the register field enumeration to connect to PF7 would be APORT2XCH23. The shared bus used by this connection is indicated in the Bus column.

**Table 5.16. ACMP0 Bus and Pin Mapping**

APORT4Y	APORT4X	APORT3Y	APORT3X	APORT2Y	APORT2X	APORT1Y	APORT1X	APORT0Y	APORT0X	Port
BUSDY	BUSDY	BUSDY	BUSCX	BUSBY	BUSBX	BUSAY	BUSAX	BUSACMP0Y	BUSACMP0X	Bus
				PB14			PB14			CH31
					PB13	PB13				CH30
				PB12			PB12			CH29
					PB11	PB11				CH28
										CH27
										CH26
										CH25
										CH24
										CH23
				PB6			PB6			CH22
	PF5	PF5			PB5	PB5				CH21
PF4			PF4	PB4			PB4			CH20
	PF3	PF3			PB3	PB3				CH19
PF2			PF2							CH18
	PF1	PF1								CH17
PF0			PF0							CH16
	PE15	PE15			PA15	PA15				CH15
PE14			PE14	PA14			PA14			CH14
	PE13	PE13			PA13	PA13				CH13
PE12			PE12							CH12
	PE11	PE11								CH11
PE10			PE10	PA10			PA10			CH10
	PE9	PE9			PA9	PA9				CH9
PE8			PE8							CH8
	PE7	PE7						PC7	PC7	CH7
PE6			PE6	PA6			PA6	PC6	PC6	CH6
	PE5	PE5			PA5	PA5		PC5	PC5	CH5
PE4			PE4	PA4			PA4	PC4	PC4	CH4
					PA3	PA3		PC3	PC3	CH3
				PA2			PA2	PC2	PC2	CH2
					PA1	PA1		PC1	PC1	CH1
				PA0			PA0	PC0	PC0	CH0



**Table 6.1. TQFP80 Package Dimensions**

Dimension	Min	Typ	Max
A	—	—	1.20
A1	0.05	—	0.15
A2	0.95	1.00	1.05
b	0.17	0.20	0.27
c	0.09	—	0.20
D	14.00 BSC		
D1	12.00 BSC		
e	0.50 BSC		
E	14.00 BSC		
E1	12.00 BSC		
L	0.45	0.60	0.75
L1	1.00 REF		
θ	0	3.5	7
aaa	0.20		
bbb	0.20		
ccc	0.08		
ddd	0.08		
eee	0.05		

**Note:**

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.
3. This package outline conforms to JEDEC MS-026, variant ADD.
4. Recommended card reflow profile is per the JEDEC/IPC J-STD-020C specification for Small Body Components.

## 9. QFN64 Package Specifications

### 9.1 QFN64 Package Dimensions

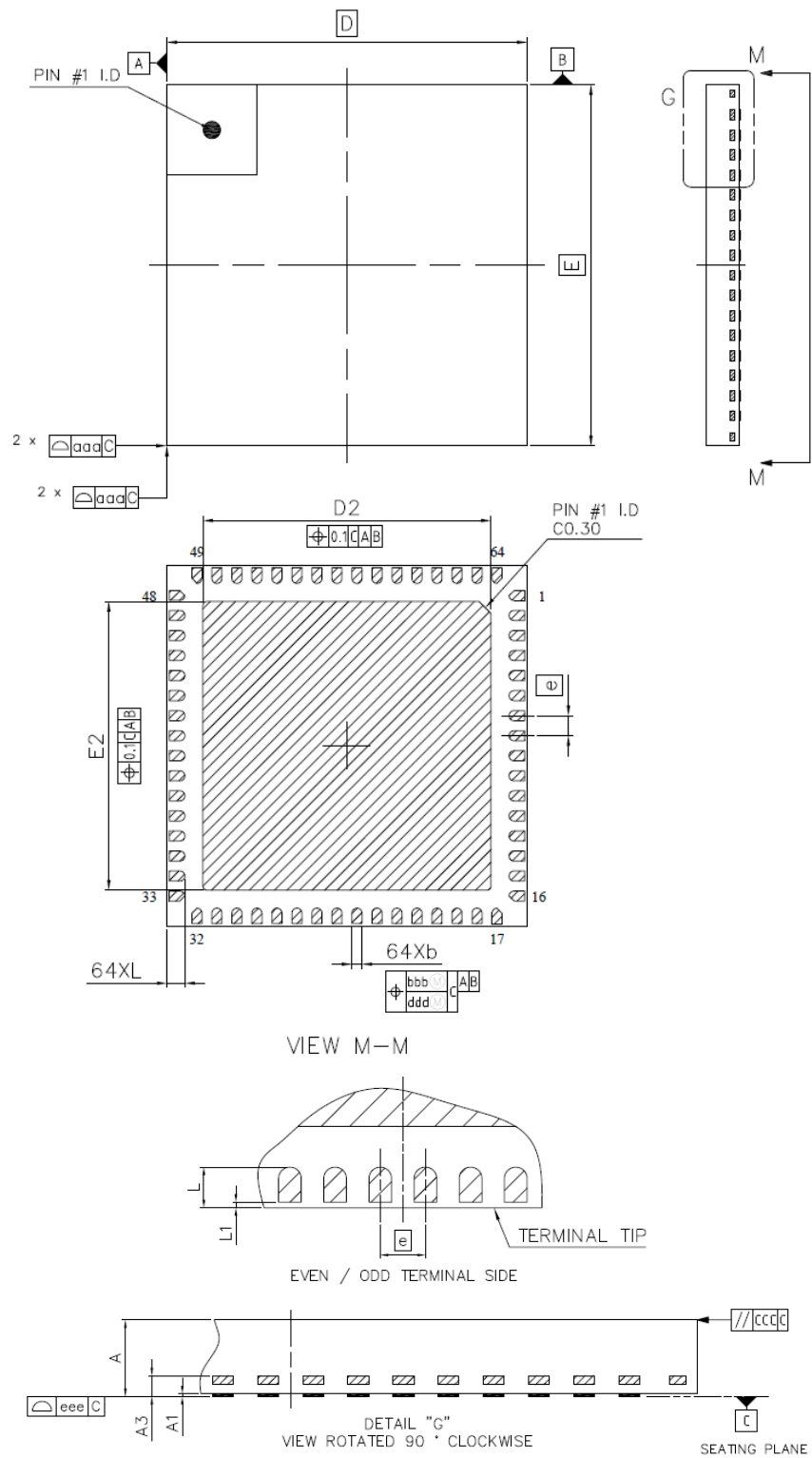


Figure 9.1. QFN64 Package Drawing

**Table 9.2. QFN64 PCB Land Pattern Dimensions**

Dimension	Typ
C1	8.90
C2	8.90
E	0.50
X1	0.30
Y1	0.85
X2	7.30
Y2	7.30

**Note:**

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. This Land Pattern Design is based on the IPC-7351 guidelines.
3. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition (LMC) is calculated based on a Fabrication Allowance of 0.05mm.
4. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.
5. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
6. The stencil thickness should be 0.125 mm (5 mils).
7. The ratio of stencil aperture to land pad size can be 1:1 for all pads.
8. A 3x3 array of 1.45 mm square openings on a 2.00 mm pitch can be used for the center ground pad.
9. A No-Clean, Type-3 solder paste is recommended.
10. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

### 9.3 QFN64 Package Marking



Figure 9.3. QFN64 Package Marking

The package marking consists of:

- P P P P P P P P P P – The part number designation.
- T T T T T T – A trace or manufacturing code. The first letter is the device revision.
- Y Y – The last 2 digits of the assembly year.
- W W – The 2-digit workweek when the device was assembled.

### 11.3 QFN32 Package Marking



Figure 11.3. QFN32 Package Marking

The package marking consists of:

- P P P P P P P P P P – The part number designation.
- T T T T T T – A trace or manufacturing code. The first letter is the device revision.
- Y Y – The last 2 digits of the assembly year.
- W W – The 2-digit workweek when the device was assembled.